30 V, P-channel Trench MOSFET

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--|--|
| 1 | G | gate | | D I |
| 2 | S | source | 누ᆜ _ | |
| 3 | D | drain | 4 3 | $G \left(\begin{array}{c} \downarrow \\ \downarrow \downarrow \\ \downarrow \downarrow \end{array} \right)$ |
| 4 | D | drain | Transparent top view DFN1010D-3 (SOT1215) | S 017aaa259 |

6. Ordering information

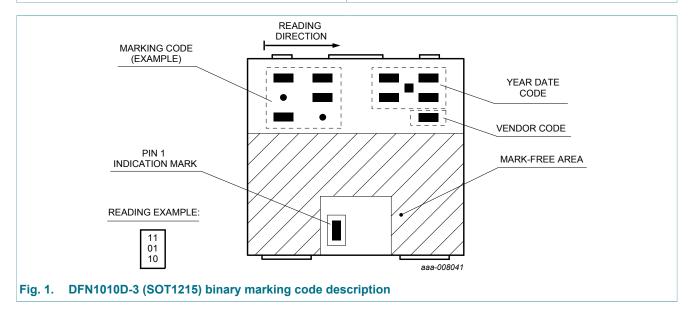
Table 3. Ordering information

| Type number | Package | | | | |
|-------------|------------|--|---------|--|--|
| | Name | Description | Version | | |
| PMXB120EPE | DFN1010D-3 | plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm | SOT1215 | | |

7. Marking

Table 4. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PMXB120EPE | 10 01 00 |



PMXB120EPE

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|---|-----|-----|------|------|
| V _{DS} | drain-source voltage | T _j = 25 °C | | - | -30 | V |
| V_{GS} | gate-source voltage | | | -20 | 20 | V |
| I _D | drain current | V_{GS} = -10 V; T_{amb} = 25 °C | [1] | - | -2.4 | Α |
| | | V _{GS} = -10 V; T _{amb} = 100 °C | [1] | - | -1.5 | Α |
| I _{DM} | peak drain current | T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$ | | - | -10 | Α |
| P _{tot} | total power dissipation | T _{amb} = 25 °C | [2] | - | 0.4 | W |
| | | | [1] | - | 1.07 | W |
| | | T _{sp} = 25 °C | | - | 8.33 | W |
| Tj | junction temperature | | | -55 | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |
| Source-dra | in diode | | ' | ' | | |
| Is | source current | T _{amb} = 25 °C | [1] | - | -0.9 | Α |

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

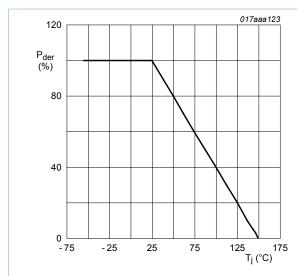


Fig. 2. Normalized total power dissipation as a function of junction temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100 \%$$

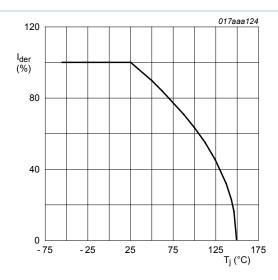


Fig. 3. Normalized continuous drain current as a function of junction temperature

$$I_{der} = \frac{I_D}{I_{D(25^{\circ}C)}} \times 100 \%$$

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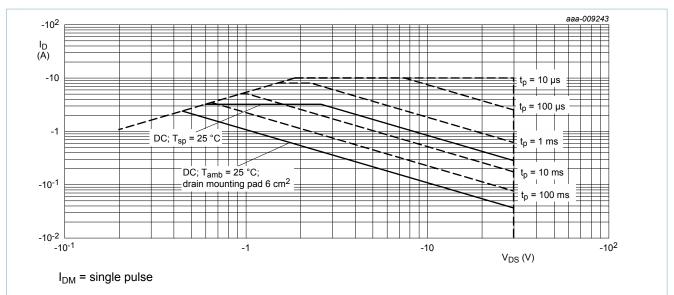


Fig. 4. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drainsource voltage

9. Thermal characteristics

Table 6. Thermal characteristics

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|-----------------------|--|-------------|-----|-----|-----|-----|------|
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | [1] | - | 271 | 312 | K/W |
| | | | [2] | - | 102 | 117 | K/W |
| R _{th(j-sp)} | thermal resistance from junction to solder point | | | - | 10 | 15 | K/W |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm².

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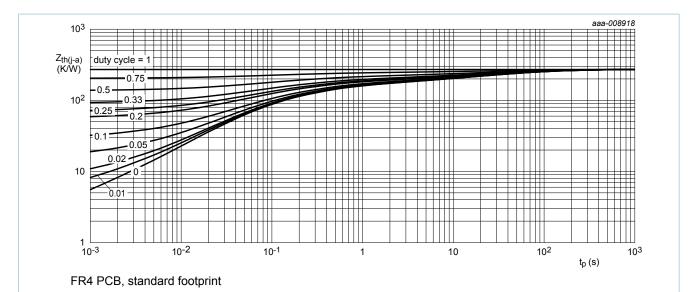


Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

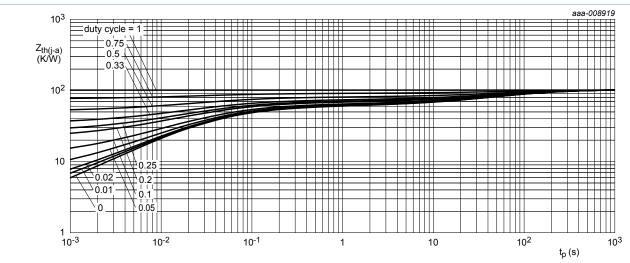


Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

FR4 PCB, mounting pad for drain $6\ \mathrm{cm}^2$

30 V, P-channel Trench MOSFET

10. Characteristics

Table 7 Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|-----------------------------------|---|-----|------|------|------|
| Static char | acteristics | | | ' | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = -250 \ \mu A; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C$ | -30 | - | - | V |
| V_{GSth} | gate-source threshold voltage | I_D = -250 μ A; V_{DS} = V_{GS} ; T_j = 25 °C | -1 | -1.5 | -2.5 | V |
| I _{DSS} | drain leakage current | V _{DS} = -30 V; V _{GS} = 0 V; T _j = 25 °C | - | - | -1 | μΑ |
| I _{GSS} | gate leakage current | V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 10 | μA |
| | | V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C | - | - | -10 | μΑ |
| | | V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C | - | - | 1 | μA |
| | | V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C | - | - | -1 | μA |
| R _{DSon} | drain-source on-state | V_{GS} = -10 V; I_D = -2.4 A; T_j = 25 °C | - | 100 | 120 | mΩ |
| | resistance | V _{GS} = -10 V; I _D = -2.4 A; T _j = 150 °C | - | 156 | 187 | mΩ |
| | | $V_{GS} = -4.5 \text{ V}; I_D = -2 \text{ A}; T_j = 25 \text{ °C}$ | - | 125 | 170 | mΩ |
| 9 _{fs} | forward transconductance | V_{DS} = -10 V; I_D = -2.4 A; T_j = 25 °C | - | 5 | - | S |
| R _G | gate resistance | f = 1 MHz | - | 14.5 | - | Ω |
| Dynamic c | haracteristics | | | ' | | , |
| Q _{G(tot)} | total gate charge | V_{DS} = -15 V; I_{D} = -2.4 A; V_{GS} = -10 V; | - | 6.2 | 11 | nC |
| Q_{GS} | gate-source charge | T _j = 25 °C | - | 0.9 | - | nC |
| Q_{GD} | gate-drain charge | | - | 1.1 | - | nC |
| C _{iss} | input capacitance | V _{DS} = -15 V; f = 1 MHz; V _{GS} = 0 V; | - | 309 | - | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 41 | - | pF |
| C _{rss} | reverse transfer capacitance | | - | 32 | - | pF |
| t _{d(on)} | turn-on delay time | V_{DS} = -15 V; I_{D} = -2.4 A; V_{GS} = -10 V; | - | 4 | - | ns |
| t _r | rise time | $R_{G(ext)} = 6 \Omega; T_j = 25 °C$ | - | 11 | - | ns |
| t _{d(off)} | turn-off delay time | | - | 16 | - | ns |
| t _f | fall time | | - | 7 | - | ns |
| Source-dra | in diode | | 1 | 1 | 1 | |
| V_{SD} | source-drain voltage | $I_S = -0.9 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | -0.8 | -1.2 | V |

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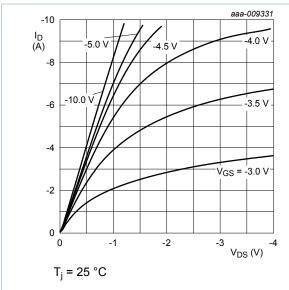


Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values

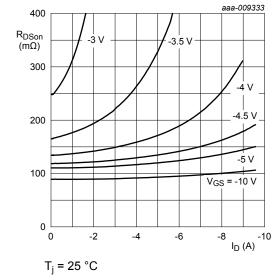


Fig. 9. Drain-source on-state resistance as a function of drain current; typical values

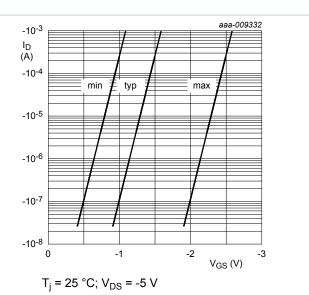


Fig. 8. Sub-threshold drain current as a function of gate-source voltage

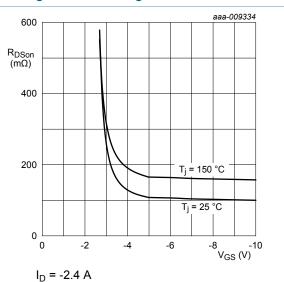


Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values

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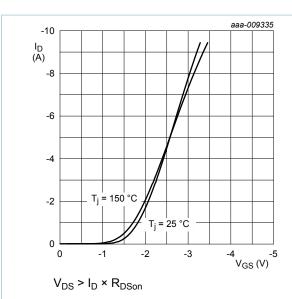


Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values

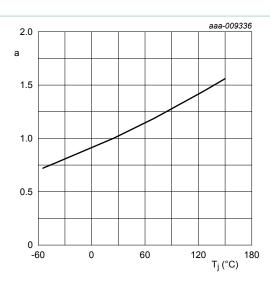


Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values

$$a = \frac{R_{DSon}}{R_{DSon(25^{\circ}C)}}$$

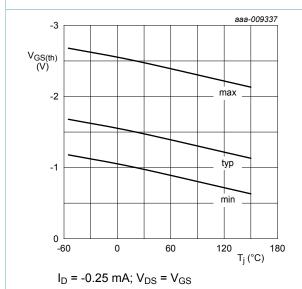


Fig. 13. Gate-source threshold voltage as a function of junction temperature

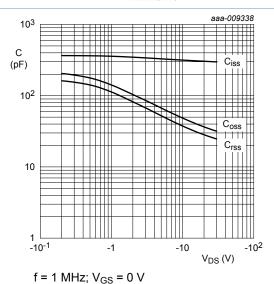


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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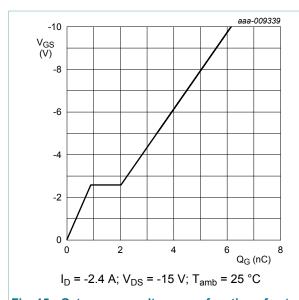


Fig. 15. Gate-source voltage as a function of gate charge; typical values

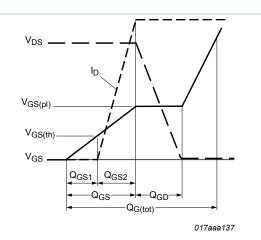


Fig. 16. MOSFET transistor: Gate charge waveform definitions

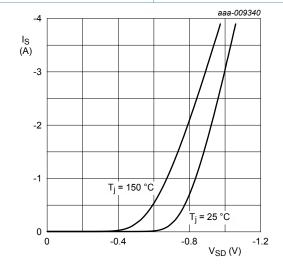
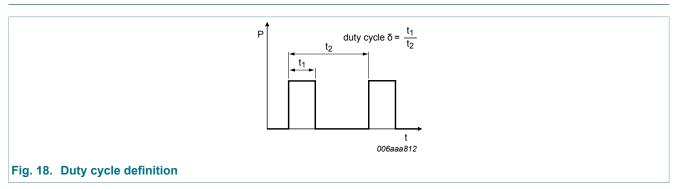


Fig. 17. Source current as a function of source-drain voltage; typical values

11. Test information

 $V_{GS} = 0 V$

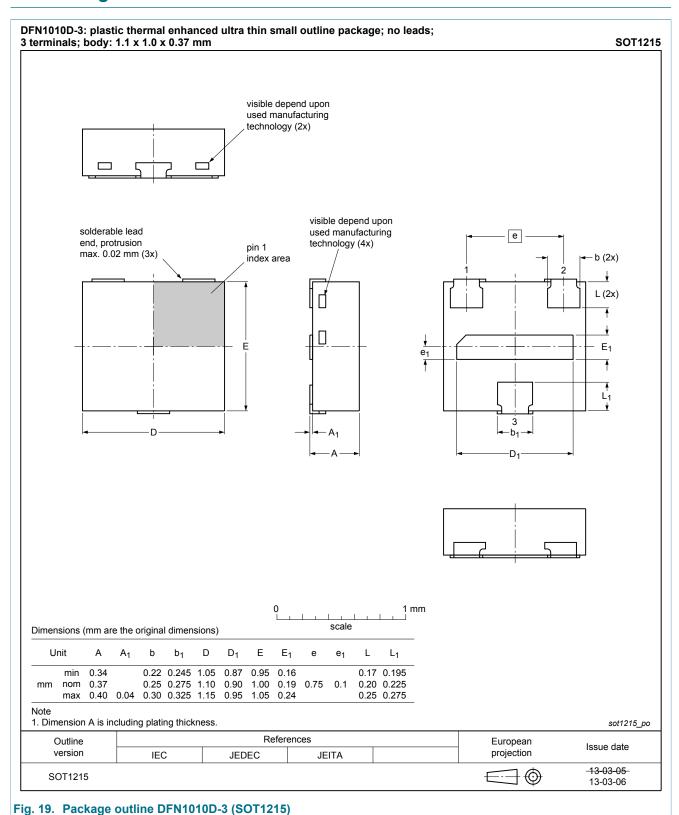


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12. Package outline

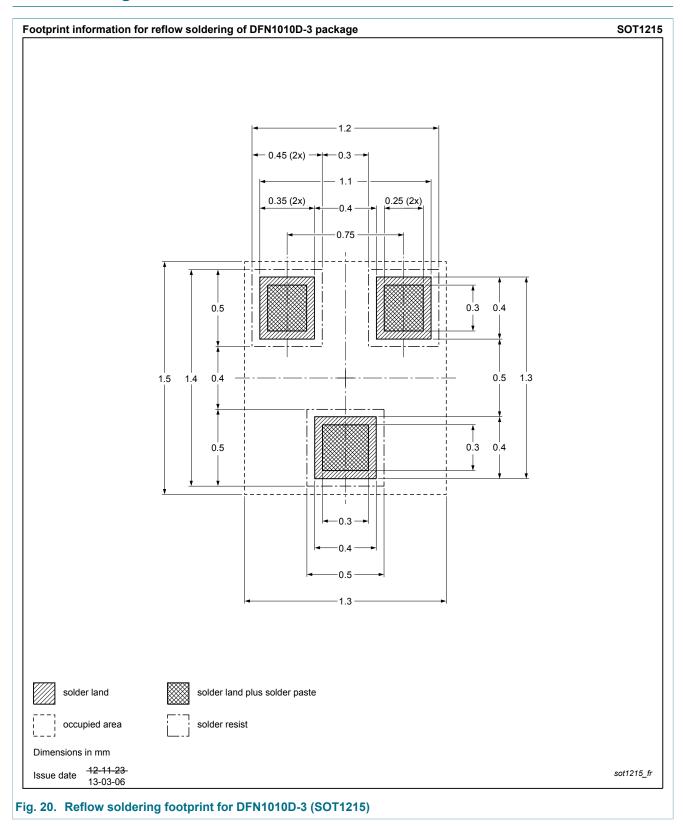


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13. Soldering



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14. Revision history

Table 8. Revision history

| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|--------------|--------------------|---------------|------------|
| PMXB120EPE v.1 | 20130924 | Product data sheet | - | - |

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